SN54AHCT374, SN74AHCT374 OCTAL EDGE-TRIGGERED D-TYPE FLIP-FLOPS WITH 3-STATE OUTPUTS

SCLS241L - OCTOBER 1995 - REVISED JULY 2003

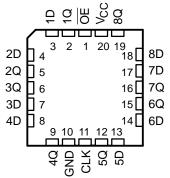
- Inputs Are TTL-Voltage Compatible
- Latch-Up Performance Exceeds 250 mA Per JESD 17

SN54AHCT374 . . . J OR W PACKAGE SN74AHCT374 . . . DB, DGV, DW, N, NS, OR PW PACKAGE (TOP VIEW)

	_			
ŌĒ	1	U	20] v _{cc}
1Q	2		19] 8Q
1D	3		18] 8D
2D	4		17] 7D
2Q			16	7Q
3Q	6		15] 6Q
3D	7		14] 6D
4D	8		13] 5D
4Q	9		12] 5Q
GND	10)	11] CLK

- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

SN54AHCT374 . . . FK PACKAGE (TOP VIEW)



description/ordering information

The 'AHCT374 devices are octal edge-triggered D-type flip-flops that feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. This device is particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

On the positive transition of the clock (CLK) input, the Q outputs are set to the logic levels of the data (D) inputs.

A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and the increased drive provide the capability to drive bus lines without interface or pullup components.

ORDERING INFORMATION

TA	PACK	AGE†	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	PDIP – N	Tube	SN74AHCT374N	SN74AHCT374N
	SOIC - DW	Tube	SN74AHCT374DW	AHCT374
	SOIC - DW	Tape and reel	SN74AHCT374DWR	AUC13/4
–40°C to 85°C	SOP - NS	Tape and reel	SN74AHCT374NSR	AHCT374
-40°C to 85°C	SSOP – DB	Tape and reel	SN74AHCT374DBR	HB374
	TSSOP – PW	Tube	SN74AHCT374PW	HB374
	1330F - FW	Tape and reel	SN74AHCT374PWR	пвэ/4
	TVSOP - DGV	Tape and reel	SN74AHCT374DGVR	HB374
	CDIP – J	Tube	SNJ54AHCT374J	SNJ54AHCT374J
–55°C to 125°C	CFP – W	Tube	SNJ54AHCT374W	SNJ54AHCT374W
	LCCC – FK Tube		SNJ54AHCT374FK	SNJ54AHCT374FK

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



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SCLS241L - OCTOBER 1995 - REVISED JULY 2003

description/ordering information (continued)

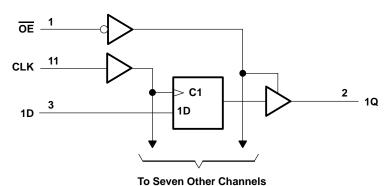
OE does not affect internal operations of the flip-flop. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

FUNCTION TABLE (each flip-flop)

	INPUTS	OUTPUT	
E	CLK	D	Q
L	1	Н	Н
L	\uparrow	L	L
L	H or L	Χ	Q_0
Н	Χ	Χ	Z

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage range, V _{CC}		–0.5 V to 7 V
Input voltage range, V _I (see Note 1)		–0.5 V to 7 V
Output voltage range, VO (see Note 1)		
Input clamp current, $I_{IK}(V_I < 0)$		–20 mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CO}	c)	±20 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$		±25 mA
Continuous current through V _{CC} or GND		±75 mA
Package thermal impedance, θ _{JA} (see Note 2)): DB package	70°C/W
	DGV package	92°C/W
	DW package	58°C/W
	N package	69°C/W
	NS package	60°C/W
	PW package	
Storage temperature range, T _{stg}		–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
 - 2. The package thermal impedance is calculated in accordance with JESD 51-7.



SCLS241L - OCTOBER 1995 - REVISED JULY 2003

recommended operating conditions (see Note 3)

		SN54AH	CT374	SN74AH	CT374	UNIT
		MIN	MAX	MIN	MAX	UNIT
VCC	Supply voltage	4.5	5.5	4.5	5.5	V
VIH	High-level input voltage	2		2		V
V _{IL}	Low-level input voltage		0.8		0.8	V
VI	Input voltage	0	5.5	0	5.5	V
VO	Output voltage	0	Vcc	0	VCC	V
ІОН	High-level output current		-8		-8	mA
l _{OL}	Low-level output current		8		8	mA
Δt/Δν	Input transition rise or fall rate		20		20	ns/V
TA	Operating free-air temperature	- 55	125	-40	85	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V	T _A = 25°C			SN54AHCT374		SN74AHCT374		UNIT
PARAMETER	TEST CONDITIONS	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
Vou	I _{OH} = -50 μA	4.5 V	4.4	4.5		4.4		4.4		V
Vон	$I_{OH} = -8 \text{ mA}$	4.5 V	3.94			3.8		3.8		٧
V _{OL}	I _{OL} = 50 μA	4.5 V			0.1		0.1		0.1	V
	I _{OL} = 8 mA	4.5 V			0.36		0.44		0.44	٧
lį	V _I = 5.5 V or GND	0 V to 5.5 V			±0.1		±1*		±1	μΑ
loz	$V_O = V_{CC}$ or GND, $V_I = V_{IH}$ or V_{IL}	5.5 V			±0.25		±2.5		±2.5	μΑ
ICC	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		40		40	μΑ
Δl _{CC} †	One input at 3.4 V, Other inputs at V _{CC} or GND	5.5 V			1.35		1.5		1.5	mA
C _i	V _I = V _{CC} or GND	5 V		4	10				10	pF
Со	V _O = V _{CC} or GND	5 V		9						pF

 $^{^{\}star}$ On products compliant to MIL-PRF-38535, this parameter is not production tested at V_{CC} = 0 V.

timing requirements over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

		T _A = 25°C		SN54AHCT374		SN74AHCT374		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	UNIT
t _W	Pulse duration, CLK high or low	6.5		6.5		6.5		ns
t _{su}	Setup time, data before CLK↑	2.5		2.5		2.5		ns
th	Hold time, data after CLK↑	2.5		2.5		2.5		ns



[†] This is the increase in supply current for each input at one of the specified TTL voltage levels, rather than 0 V or VCC.

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SCLS241L - OCTOBER 1995 - REVISED JULY 2003

switching characteristics over recommended free-air temperature operating range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T	A = 25°(3	SN54AI	HCT374	SN74AH	CT374	UNIT				
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT				
f			C _L = 15 pF	90**	140**		80**		80		MHz				
f _{max}			C _L = 50 pF	85	130		75		75		IVITIZ				
^t PLH	CLK	Q	C 15 pE		5.6**	9.4**	1**	10.5**	1	10.5	ns				
^t PHL	CLK	Q	C _L = 15 pF		5.6**	9.4**	1**	10.5**	1	10.5	116				
^t PZH		Q	C 15 pE		6.5**	10.2**	1**	11.5**	1	11.5	20				
^t PZL	ŌĒ	Q	Q	Q	Q	C _L = 15 pF		6.5**	10.2**	1**	11.5**	1	11.5	ns	
^t PHZ	ŌĒ	Q	C _I = 15 pF		6.2**	10.2**	1**	11**	1	11	ns				
tPLZ	OE		Q	Q	Q	ν	ų.	OL = 13 pr		6.2**	10.2**	1**	11**	1	11
t _{PLH}	CLK	Q	C: 50 pF		6.4	10.4	1	11.5	1	11.5					
^t PHL	CLK	Q	C _L = 50 pF		6.4	10.4	1	11.5	1	11.5	ns				
^t PZH		0	C: - 50 pF		7.3	11.2	1	12.5	1	12.5	no				
^t PZL	ŌĒ	Q	$C_L = 50 pF$		7.3	11.2	1	12.5	1	12.5	ns				
^t PHZ	ŌĒ	Q	C: - 50 pF		7	11.2	1	12	1	12	no				
t _{PLZ}	OE	٧	C _L = 50 pF		7	11.2	1	12	1	12	ns				
tsk(o)			C _L = 50 pF			1***				1	ns				

^{**} On products compliant to MIL-PRF-38535, this parameter is not production tested.

noise characteristics, $V_{CC} = 5 \text{ V}$, $C_L = 50 \text{ pF}$, $T_A = 25^{\circ}\text{C}$ (see Note 4)

	PARAMETER -		SN74AHCT374			
			TYP	MAX	UNIT	
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.8	1.2	V	
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		-0.8	-1.2	V	
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}	3.8			V	
VIH(D)	High-level dynamic input voltage	2			V	
V _{IL(D)}	Low-level dynamic input voltage			8.0	V	

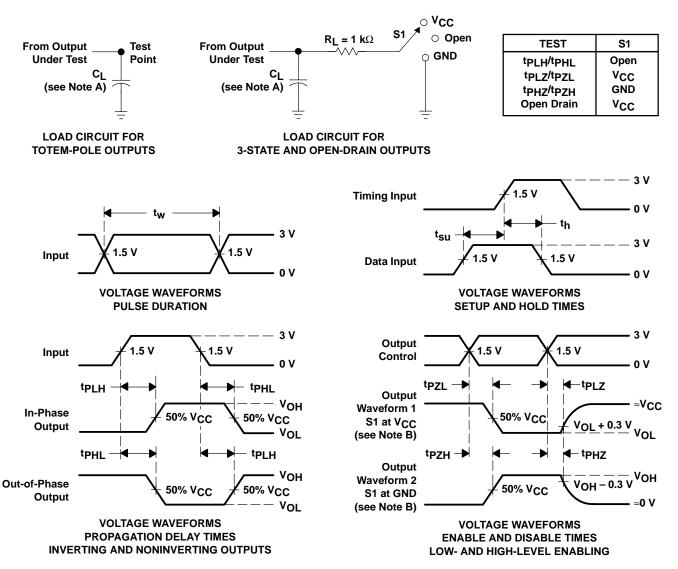
NOTE 4: Characteristics are for surface-mount packages only.

operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

PARAMETER			ONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load,	f = 1 MHz	27	pF

^{***} On products compliant to MIL-PRF-38535, this parameter does not apply.

PARAMETER MEASUREMENT INFORMATION



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_f \leq 3$ ns. $t_f \leq 3$ ns.
 - D. The outputs are measured one at a time with one input transition per measurement.
 - E. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

